

# SSM3J111TU

## High Speed Switching Applications

- 2.5V drive
- Low on-resistance:  $R_{on} = 480\text{m}\Omega$  (max) (@ $V_{GS} = -4\text{ V}$ )  
 $R_{on} = 680\text{m}\Omega$  (max) (@ $V_{GS} = -2.5\text{ V}$ )

## Absolute Maximum Ratings (Ta = 25°C)

Characteristic		Symbol	Rating	Unit
Drain-Source voltage		$V_{DS}$	-20	V
Gate-Source voltage		$V_{GSS}$	$\pm 12$	V
Drain current	DC	$I_D$	-1	A
	Pulse	$I_{DP}$	-2	
Drain power dissipation		$P_D$ (Note 1)	800	mW
		$P_D$ (Note 2)	500	
Channel temperature		$T_{ch}$	150	°C
Storage temperature range		$T_{stg}$	-55~150	°C

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.  
 Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 1: Mounted on ceramic board.  
 (25.4 mm × 25.4 mm × 0.8 mm, Cu Pad: 645 mm<sup>2</sup>)

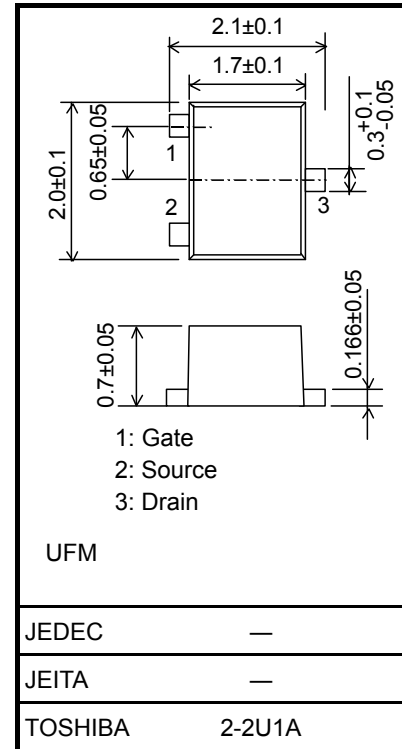
Note 2: Mounted on FR4 board.  
 (25.4 mm × 25.4 mm × 1.6 mm, Cu Pad: 645 mm<sup>2</sup>)

## Electrical Characteristics (Ta = 25°C)

Characteristic		Symbol	Test Conditions	Min	Typ.	Max	Unit
Drain-Source breakdown voltage		$V_{(BR) DSS}$	$I_D = -1\text{ mA}, V_{GS} = 0$	-20	—	—	V
Drain cut-off current		$I_{DSS}$	$V_{DS} = -20\text{ V}, V_{GS} = 0$	—	—	-1	μA
Gate leakage current		$I_{GSS}$	$V_{GS} = \pm 12\text{ V}, V_{DS} = 0$	—	—	±1	μA
Gate threshold voltage		$V_{th}$	$V_{DS} = -3\text{ V}, I_D = -0.1\text{ mA}$	-0.6	—	-1.1	V
Forward transfer admittance		$ Y_{fs} $	$V_{DS} = -3\text{ V}, I_D = -0.3\text{ A}$ (Note3)	0.6	1.2	—	S
Drain-Source on-resistance		$R_{DS(ON)}$	$I_D = -0.3\text{ A}, V_{GS} = -4.0\text{ V}$ (Note3)	—	380	480	mΩ
			$I_D = -0.3\text{ A}, V_{GS} = -2.5\text{ V}$ (Note3)	—	530	680	
Input capacitance		$C_{iss}$	$V_{DS} = -10\text{ V}, V_{GS} = 0, f = 1\text{ MHz}$	—	160	—	pF
Output capacitance		$C_{oss}$	$V_{DS} = -10\text{ V}, V_{GS} = 0, f = 1\text{ MHz}$	—	90	—	pF
Reverse transfer capacitance		$C_{rss}$	$V_{DS} = -10\text{ V}, V_{GS} = 0, f = 1\text{ MHz}$	—	25	—	pF
Switching time	Turn-on time	$t_{on}$	$V_{DD} = -10\text{ V}, I_D = -0.3\text{ A},$ $V_{GS} = 0 \sim -2.5\text{ V}, R_G = 4.7\ \Omega$	—	27	—	ns
	Turn-off time	$t_{off}$		—	43	—	
Drain-Source forward voltage		$V_{DSF}$	$I_D = 1\text{ A}, V_{GS} = 0\text{ V}$ (Note3)	—	0.85	1.2	V

Note3: Pulse test

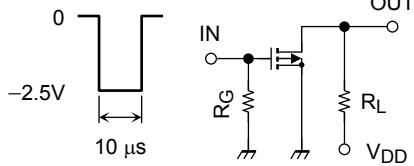
Unit: mm



Weight: 6.6 mg (typ.)

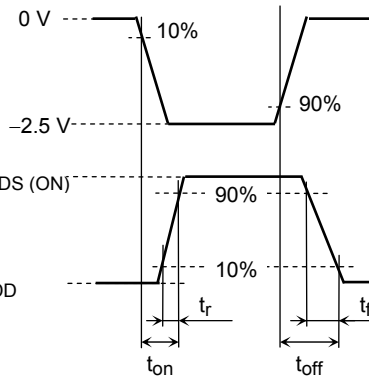
**Switching Time Test Circuit**

**(a) Test circuit**

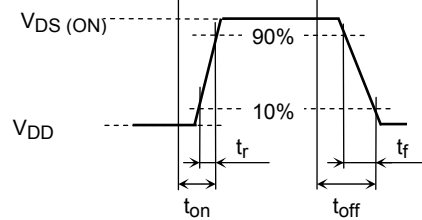


$V_{DD} = -10\text{ V}$   
 $R_G = 4.7\ \Omega$   
 D.U.  $\leq 1\%$   
 $V_{IN}$ :  $t_r, t_f < 5\text{ ns}$   
 Common Source  
 $T_a = 25^\circ\text{C}$

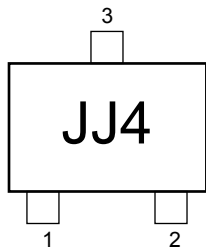
**(b)  $V_{IN}$**



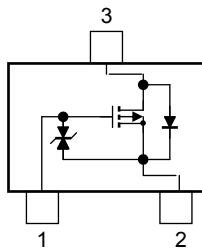
**(c)  $V_{OUT}$**



**Marking**



**Equivalent Circuit (top view)**



**Precaution**

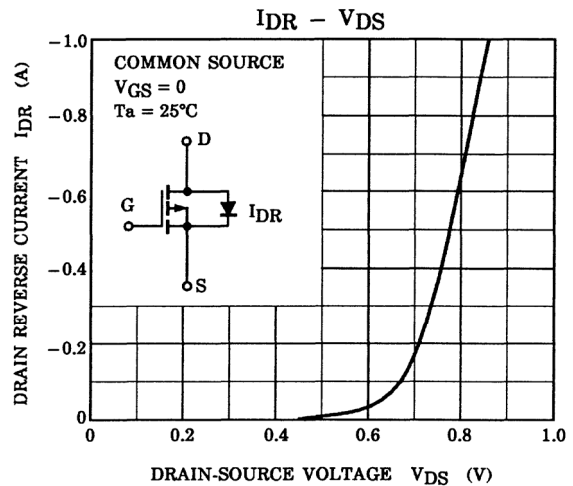
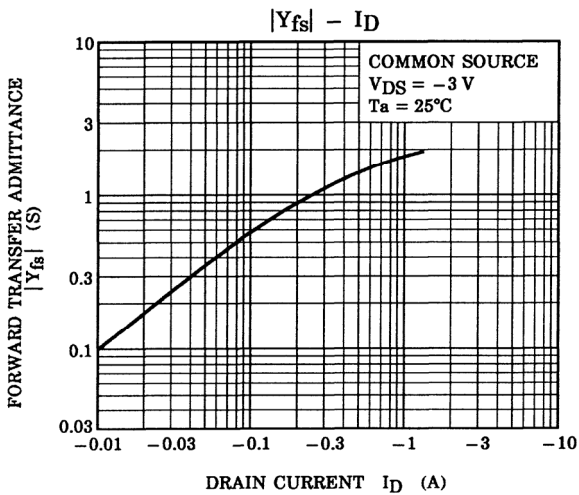
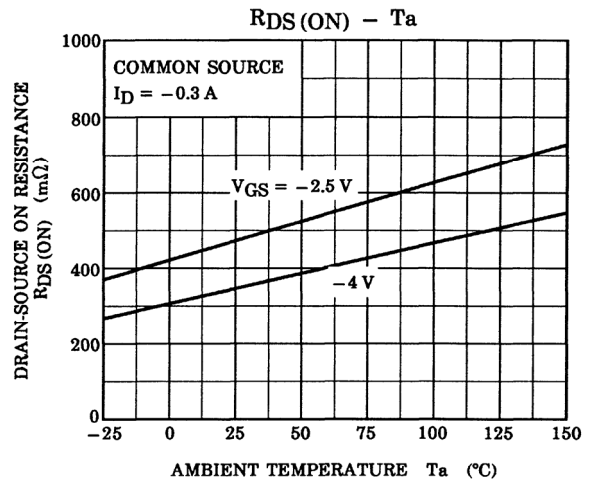
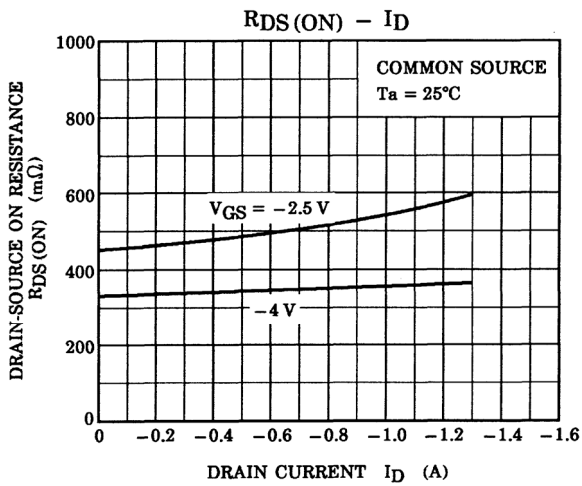
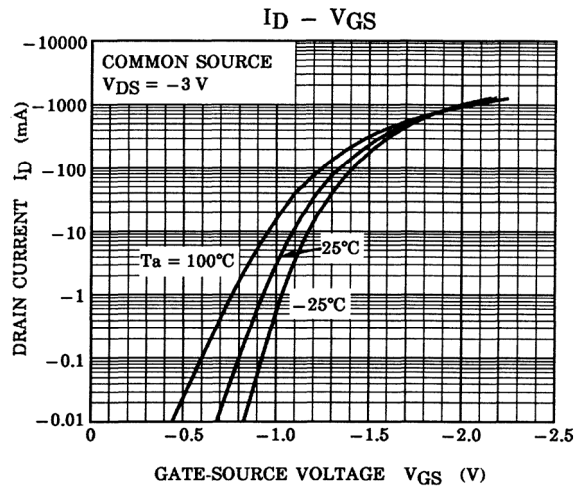
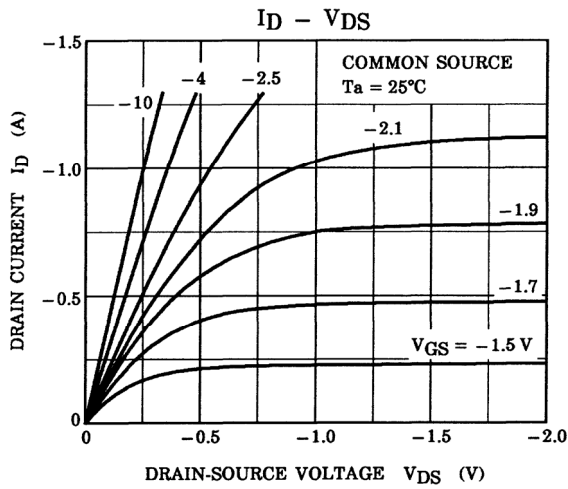
$V_{th}$  can be expressed as the voltage between gate and source when the low operating current value is  $I_D = -0.1\text{ mA}$  for this product. For normal switching operation,  $V_{GS (on)}$  requires a higher voltage than  $V_{th}$ , and  $V_{GS (off)}$  requires a lower voltage than  $V_{th}$ .

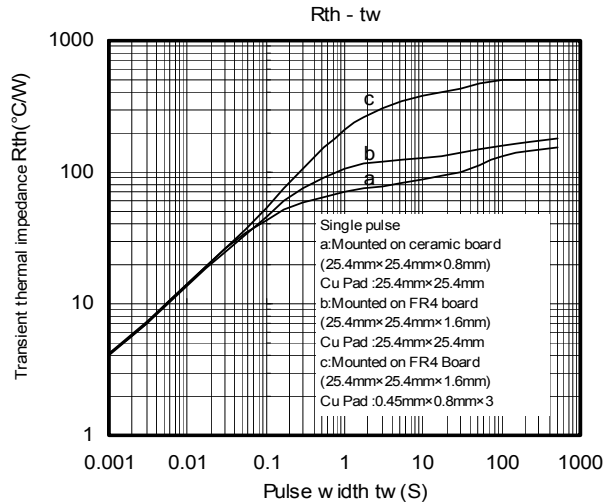
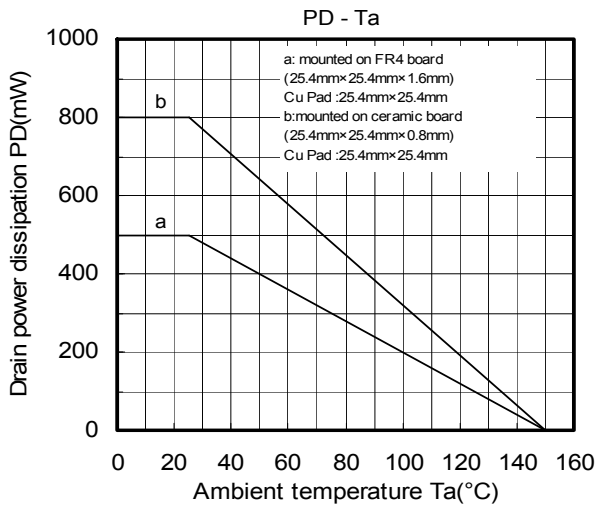
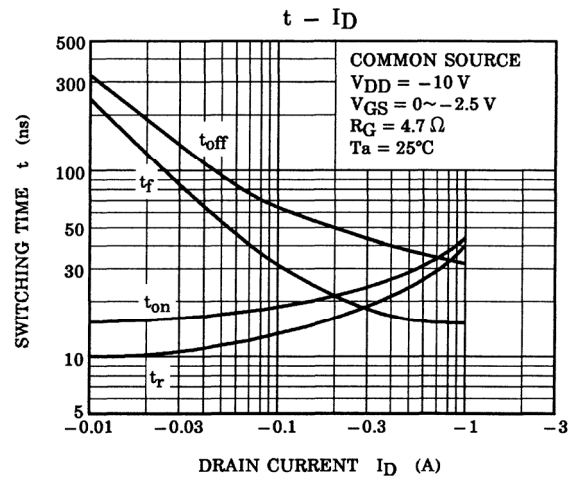
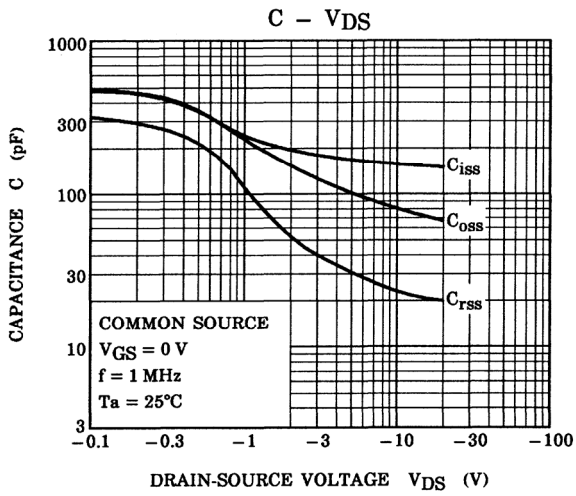
(The relationship can be established as follows:  $V_{GS (off)} < V_{th} < V_{GS (on)}$ )

Take this into consideration when using the device.

**Handling Precaution**

When handling individual devices which are not yet mounted on a circuit board, be sure that the environment is protected against electrostatic discharge. Operators should wear anti-static clothing, and containers and other objects that come into direct contact with devices should be made of anti-static materials.





**RESTRICTIONS ON PRODUCT USE**

20070701-EN GENERAL

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